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**GP1S525VJ00F Sales and Technical Information**

PRODUCT DETAIL INFORMATION	
Attribute Name	Attribute Data
Family	GP1S525VJ00F
Gap	5.0 mm
Output Signal	Phototransistor
RoHS	Yes
Slit Width	0.5 mm
Status	<b>Production</b>
Type	Transmissive

DISTRIBUTOR INVENTORY			
Part Number	Distributor	Quantity	Inv. Date
GP1S525VJ00F	<a href="#">DIGI -KEY CORPORATION</a>	113	2/25/2009

GP1S525VJ00F DOCUMENTATION				
Document Type	Document Name	Format	Size	Revision Date
PCN	<a href="#">PCN-20070504 -01</a> Photointerrupters:Internal Chip Change. The infrared emitter chips used in the listed Sharp devices will be changed to allow for a more stable source of supply. This change will take place as a running change to production beginning in June, 2007.	pdf	30.5K	5/4/2007

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